

Description

The AU1521P0 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU1521P0 complies with the IEC 61000-4-2 (ESD) with ±30 kV air and ±30 kV contact discharge. It is assembled into an ultra-small 0.6x0.3x0.3mm lead-free DFN package. The small size and high ESD surge protection make AU1521P0 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- Ultra small package: 0.6x0.3x0.3mm
- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 15V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 2.5A (8/20µs)
- RoHS Compliant

Mechanical Characteristics

- Package: DFN0603-2 (0.6×0.3×0.3mm)
- Case Material: "Green" Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

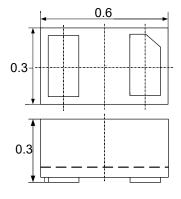
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

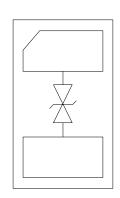
Marking Information



Ordering Information

Dimensions and Pin Configuration





Part Number	Packaging	Reel Size
AU1521P0	10000/Tape & Reel	7 inch

Package Dimensions

Circuit and Pin Schematic



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

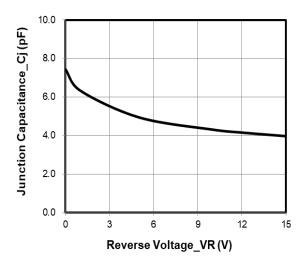
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	65	W
Peak Pulse Current (8/20µs)	IPP	2.5	Α
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±30 ±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

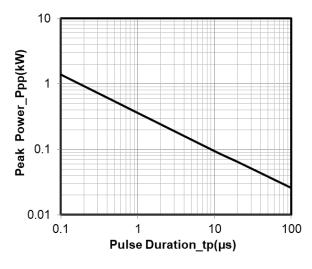
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			15	V	
Breakdown Voltage	VBR	16.5			V	IT = 1mA
Reverse Leakage Current	I _R			0.2	μA	VRWM = 15V
Clamping Voltage	Vc			22	V	IPP = 1A
Clamping Voltage	Vc			26	V	IPP = 2.5A
Junction Capacitance	Сл		7.5	10	pF	VR = 0V, f = 1MHz

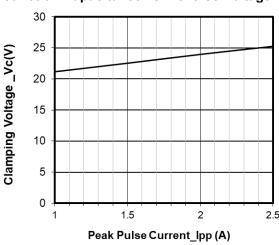


Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

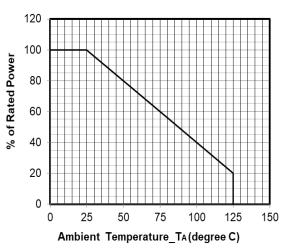




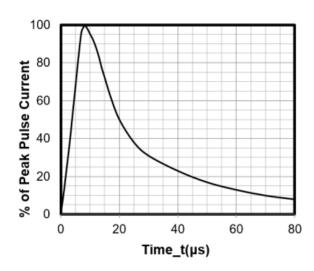
Junction Capacitance vs. Reverse Voltage



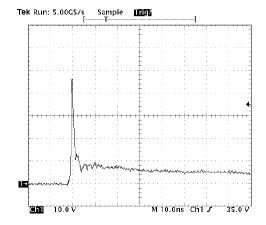
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current (tp = 8/20µs)



Power Derating Curve



8 X 20µs Pulse Waveform

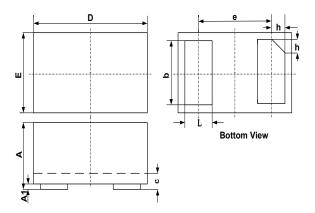
Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

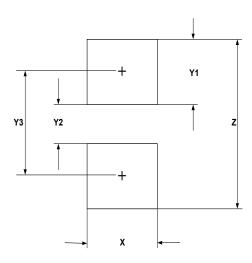


DFN0603-2 Package Outline Drawing



	DIMENSIONS				
	MILLIMETERS				
SYM	MIN	NOM		MAX	
Α	0.230			0.330	
A1	0.000	0.020		0.050	
b	0.215	0.245		0.275	
С	0.120	0.150		0.180	
D	0.550	0.600		0.650	
е	0.355 BSC				
Е	0.250	0.300		0.350	
L	0.160	0.190		0.220	
h	0.079 BSC				

Suggested Land Pattern



SYM	DIMENSIONS				
	MILLIMETERS	INCHES			
Х	0.30	0.012			
Y1	0.25	0.010			
Y2	0.15	0.006			
Y3	0.40	0.016			
Z	0.65	0.026			

Contact Information

Applied Power Microelectronics Inc.

Website: http://www.appliedpowermicro.com

Email: sales@appliedpowermicro.com

Phone: +86 (0519) 8399 3606

Applied Power Microelectronics Inc. (APM) reserves the right to make changes to the product specification and data in this document without notice. APM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does APM assume any liability arising from the application or use of any products or circuits, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.